

Dear Member,

The following document is being circulated for vote at CENELEC level:

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Reference document : IEC 61000-4-6 ED5 (77B/856/CDV) (EQV)

Title : Electromagnetic compatibility (EMC) - Part 4-6: Testing and measurement

techniques - Immunity to conducted disturbances, induced by radio-frequency

fields

Technical Body : CLC/TC 210 IEC/TC : IEC/SC 77B

Procedure : Parallel Vote on CDV

BT decision : -

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 : 2022-04-15

 Deadline
 : 2022-07-08

 doa
 : dor + 3 months

 dop
 : dor + 9 months

 dow
 : dor + 36 months

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(Acting) Secretary : Ms Nyomee Hla-Shwe Tun

Assistant Secretary :

Chairman/Convenor : Mr John H Davies

Permanent Delegate : c.c : CCMC comment : -

CCMC general remarks:

- The National Committees are invited to check carefully the validity of the proposed implementation dates and Directive(s).
- Superseded documents are withdrawn at the dow of the new EN/HD or at the publication date of the new TS/TR.
- If the above project is submitted simultaneously to the IEC voting procedure in the framework of the IEC/CENELEC cooperation agreement (parallel procedure) you will receive the text of the document from the IEC Central Office. Should your vote be different in IEC and CENELEC, a detailed technical justification shall be sent to the CCMC, with copy to the IEC Central Office.
- If the above project is an amendment circulated to withdraw special national conditions and/or A-deviations from a standard the National Committees are invited to check their national situation regarding the same standard and to inform the CCMC of any change, with a copy to the Secretary of the relevant Technical Body. There is no possibility to vote through the usual online voting system.

Yours sincerely,

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COMMITTEE DRAFT FOR VOTE (CDV)

CLOSING DATE FOR VOTING:

2022-07-08

	SUPERSEDES DOCU	MENTS:	
	77B/843/CD, 77E	3/854/CC	
IFC SC 77B : HIGH EDECHENOV BUENO	NATALA		
IEC SC 77B : HIGH FREQUENCY PHENO	MENA	0	
SECRETARIAT:		SECRETARY:	
France		Mr Franck GRUFFAZ	
OF INTEREST TO THE FOLLOWING COMM	ITTEES:	PROPOSED HORIZONTAL STANDARD:	
TC 61,CIS/F,CIS/H			
		Other TC/SCs are requested to indicate their interest, if any, in this CDV to the secretary.	
FUNCTIONS CONCERNED:			
	CONMENT	Quality assurance Safety	
SUBMITTED FOR CENELEC PARALLE	L VOTING	☐ NOT SUBMITTED FOR CENELEC PARALLEL VOTING	
Attention IEC-CENELEC parallel vo	ting		
The attention of IEC National Committees, members of CENELEC, is drawn to the fact that this Committee Draft for Vote (CDV) is submitted for parallel voting.			
The CENELEC members are invited to vote through the CENELEC online voting system.			
This document is still under study and	d subject to change.	It should not be used for reference purposes.	
Recipients of this document are invited to submit, with their comments, notification of any relevant patent rights of which they are aware and to provide supporting documentation.			
TITLE:			
Electromagnetic compatibility (Immunity to conducted disturba		Testing and measurement techniques - y radio-frequency fields	
PROPOSED STABILITY DATE: 2027			
NOTE FROM TC/SC OFFICERS:			

PROJECT NUMBER: IEC 61000-4-6 ED5

2022-04-15

DATE OF CIRCULATION:

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